

## The RF Line UHF Power Amplifiers

Designed specifically for the Pan European digital 2.0 watt, GSM hand-held radio. The MHW953 and MHW954 are capable of wide power range control, operate from a 7.2 volt supply and require 1.0 mW (MHW953) or 100 mW (MHW954) of RF input power.

- Specified 7.2 Volt Characteristics:
  - RF Input Power — 1.0 mW (0 dBm) MHW953; 100 mW (20 dBm) MHW954
  - RF Output Power — 3.5 W
  - Minimum Gain — 35.4 dB (MHW953) or 15.4 dB (MHW954)
  - Harmonics — -35 dBc Max @ 2.0  $f_o$  (MHW953) or  
-30 dBc Max @ 2.0  $f_o$  (MHW954)
- New Biasing and Control Techniques Providing Dynamic Range and Control Circuit Bandwidth Ideal for GSM
- Low Control Current
- 50 Ohm Input/Output Impedances
- Guaranteed Stability and Ruggedness
- Test fixture circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

### MAXIMUM RATINGS (Flange Temperature = 25°C)

Rating	Symbol	Value	Unit
DC Supply Voltage	$V_{S1}, V_{S2}, V_{S3}$	9.0	Vdc
DC Bias Voltage (MHW953) (MHW954)	$V_b$	5.25 4.75	Vdc
DC Control Voltage (MHW953 only)	$V_{cont}$	3.0	Vdc
RF Input Power (MHW953) (MHW954)	$P_{in}$	2.0 400	mW
RF Output Power ( $V_S = 9.0$ Vdc)	$P_{out}$	4.5	W
Operating Case Temperature Range Storage Temperature Range	$T_C$ $T_{stg}$	-30 to +100	°C

**ELECTRICAL CHARACTERISTICS** ( $V_{S1} = V_{S2} = V_{S3} = 7.2$  Vdc;  $V_b = 5.0$  Vdc for MHW953)  
 ( $V_{S1} = V_{S2} = 7.2$  Vdc;  $V_b = 4.5$  Vdc for MHW954)  
 ( $T_C = 25^\circ\text{C}$ ; 50 ohm system, unless otherwise noted)

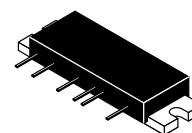
Characteristic	Symbol	Min	Max	Unit
Frequency Range	BW	890	915	MHz
Power Gain ( $P_{out} = 3.5$ mW) MHW953 (1) MHW954 (2)	Gp	35.4 15.4	— —	dB
Control Current ( $P_{out} = 3.5$ W; $P_{in} = 1.0$ mW) MHW953 only (1)	$I_{cont}$	—	1.0	mA
Supply Current ( $P_{out} = 3.5$ W; $P_{in} = 1.0$ mW) MHW953 only (1)	$I_b$	—	85	mA
Leakage Current ( $P_{in} = 0$ mW; $V_{cont} = V_b = 0$ Vdc; $V_{S1} = V_{S2} = V_{S3} = 9.0$ Vdc for MHW953. $P_{in} = 0$ mW; $V_b = 0$ Vdc; $V_{S1} = V_{S2} = 9.0$ Vdc for MHW954)	$I_L$	— —	1.0 200	mA $\mu\text{A}$
Input VSWR ( $P_{out} = 3.5$ W; $P_{in} = 1.0$ mW) MHW953 (1) ( $P_{out} = 3.5$ W) MHW954 (2)	VSWR <sub>in</sub>	—	2.0:1	—

#### NOTES:

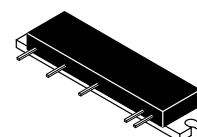
- Adjust  $V_{cont}$  for specified  $P_{out}$ ; duty cycle = 12.5%, period = 4.6 ms
- Adjust  $P_{in}$  for specified  $P_{out}$ ; duty cycle = 12.5%, period = 4.6 ms

**MHW953**  
**MHW954**

**3.5 W**  
**890 to 915 MHz**  
**RF POWER**  
**AMPLIFIERS**



**CASE 301V-02, STYLE 1**  
**(MHW953)**



**CASE 301Y-02, STYLE 1**  
**(MHW954)**



# ELECTRICAL CHARACTERISTICS — continued ( $V_{S1} = V_{S2} = V_{S3} = 7.2$ Vdc; $V_b = 5.0$ Vdc for MHW953)

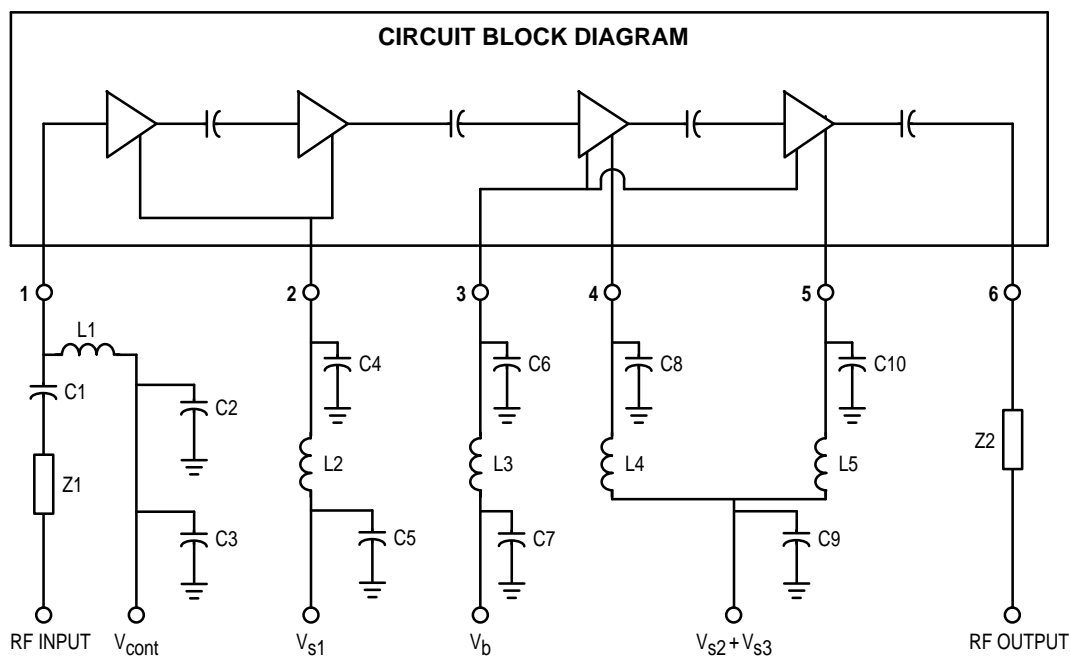
( $V_{S1} = V_{S2} = 7.2$  Vdc;  $V_b = 4.5$  Vdc for MHW954)

( $T_C = 25^\circ\text{C}$ ; 50 ohm system, unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Efficiency ( $P_{\text{out}} = 3.5$ W; $P_{\text{in}} = 1.0$ mW) MHW953 (1) ( $P_{\text{out}} = 3.5$ W) MHW954 (2)	$\eta$	40	—	%
Harmonics ( $P_{\text{out}} = 3.5$ W; $P_{\text{in}} = 1.0$ mW) MHW953 (1) $2.0 f_o$ $3.0 f_o$ ( $P_{\text{out}} = 3.5$ W) MHW954 (2) $2.0 f_o$ $3.0 f_o$	—	— — — —	—35 —45 —30 —40	dBc
Noise Power (In 30 kHz Bandwidth, 20 MHz above $f_o$ ) ( $T_C = 25^\circ\text{C} - 100^\circ\text{C}$ ) ( $P_{\text{out}} = 0.3 - 3.5$ W; $V_{S1} = V_{S2} = V_{S3} = 6.25 - 9.0$ Vdc, $P_{\text{in}} = 1.0$ mW) MHW953 (1) ( $P_{\text{out}} = 0.3 - 3.5$ W; $V_{S1} = V_{S2} = 6.25 - 9.0$ Vdc) MHW954 (2)	—	— —	—65 —75	dBm
Output Power, Low Voltage ( $P_{\text{in}} = 1.0$ mW; $V_{S1} = V_{S2} = V_{S3} = 6.25$ Vdc; $V_{\text{cont}} = 3.0$ Vdc) MHW953 ( $P_{\text{in}} = 100$ mW; $V_{S1} = V_{S2} = 6.25$ Vdc) MHW954	$P_{O1}$	2.0 2.3	— —	W
Isolation ( $P_{\text{in}} = 1.0$ mW; $V_{\text{cont}} = 0$ Vdc; $V_{S1} = V_b = 0 - 5$ Vdc) MHW953 only (1)	—	—	—36	dBm
3.0 dB $V_{\text{cont}}$ Bandwidth ( $P_{\text{in}} = 1.0$ mW; $P_{\text{out}} = 0.03 - 3.5$ W) MHW953 only (1)	—	1.0	—	MHz
% AM In Output ( $P_{\text{out}} = 0.035 - 3.5$ W; 135 kHz, 1% AM on Input) MHW954 only (2)	—	—	6	%
Load Mismatch Stress ( $P_{\text{in}} = 2.0$ mW; $P_{\text{out}} = 3.5$ W; $V_{S1} = V_{S2} = V_{S3} = 9.0$ Vdc) MHW953 (1) ( $P_{\text{out}} = 3.5$ W; $V_b = 4.75$ Vdc; $V_{S1} = V_{S2} = 9.0$ Vdc) MHW954 (2) (Load VSWR = 10:1, All Phase Angles at Frequency of Test)	$\psi$	No degradation in output power before and after test		
Stability ( $P_{\text{in}} = 0.5$ to $2.0$ mW; $P_{\text{out}} = 0.03 - 3.5$ W; $V_{S1} = V_{S2} = V_{S3} = 6.0$ to $9.0$ Vdc) MHW953 (1) ( $P_{\text{out}} = 0.03 - 3.5$ W; $V_{S1} = V_{S2} = 6.0$ to $9.0$ Vdc) MHW954 (2) (Load VSWR = 6:1, Source VSWR = 3:1, All Phase Angles at Frequency of Test)	—	All spurious outputs more than 60 dB below desired signal		

## NOTES:

1. Adjust  $V_{\text{cont}}$  for specified  $P_{\text{out}}$ ; duty cycle = 12.5%, period = 4.6 ms
2. Adjust  $P_{\text{in}}$  for specified  $P_{\text{out}}$ ; duty cycle = 12.5%, period = 4.6 ms



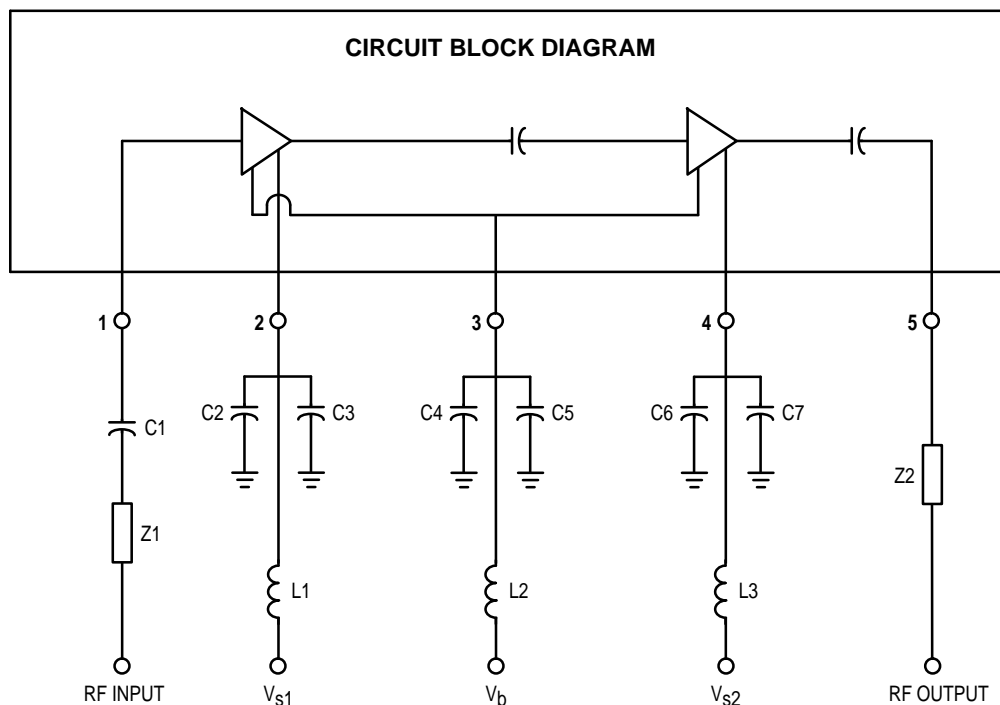
## PIN DESIGNATIONS:

Pin 1 — RF Input Power @ 0 dBm and Control Voltage @ 0–3.0 Vdc  
Pin 2 — First and Second Stage Collector Supply Voltage @ 7.2 Vdc  
Pin 3 — Trickle Base Bias Voltage @ 5.0 Vdc  
Pin 4 — Third Stage Collector Supply Voltage @ 7.2 Vdc  
Pin 5 — Fourth Stage Collector Supply Voltage @ 7.2 Vdc  
Pin 6 — RF Output Power @ 3.5 W

## ELEMENT VALUES:

$C1 = C2 = 0.018$   $\mu\text{F}$   
 $C4 = C6 = C8 = C10 = 0.1$   $\mu\text{F}$   
 $C3 = C5 = C7 = C9 = 1.0$   $\mu\text{F}$  Tant.  
 $L1 - L3 = 0.29$   $\mu\text{H}$  Choke  
 $L4, L5 = 0.15$   $\mu\text{H}$  Choke  
 $Z1, Z2 = 50$  Ohm Microstrip

Figure 1. Test Circuit Diagram — MHW953



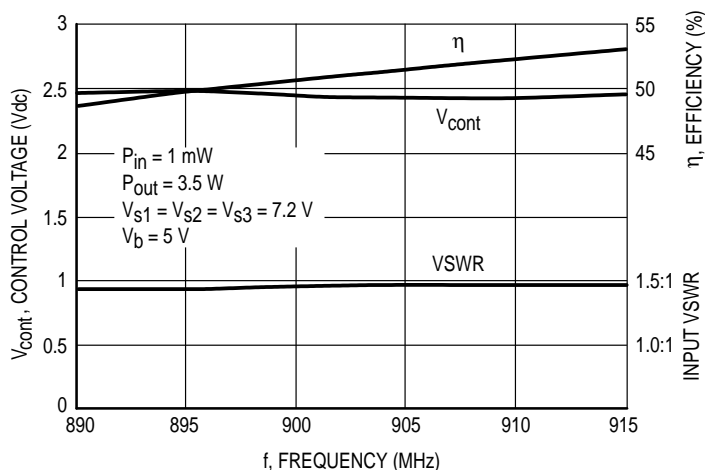
**PIN DESIGNATIONS:**

Pin 1 — RF Input Power @ 20 dBm Max Adjust for Output Power  
 Pin 2 — First Stage Collector Voltage @ 7.2 Vdc  
 Pin 3 — Trickle Bias Voltage @ 4.5 Vdc  
 Pin 4 — Third Stage Collector Supply @ 7.2 Vdc  
 Pin 5 — RF Output Power @ 3.5 W Nominal

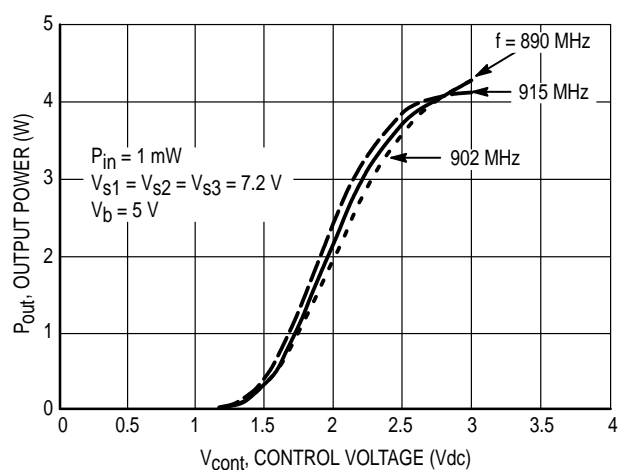
**ELEMENT VALUES:**

$C1=C2=C4=C6= 0.018 \mu\text{F}$   
 $C3=C5=C7= 2.2 \mu\text{F}$   
 $L1, L2 = 0.29 \mu\text{H}$   
 $L3 = 0.2 \mu\text{H}$   
 $Z1, Z2 = 50 \text{ Ohm Microstrip}$

**Figure 2. Test Circuit Diagram — MHW954**



**Figure 3. Control Voltage, Efficiency and Input VSWR versus Frequency**



**Figure 4. Output Power versus Control Voltage**

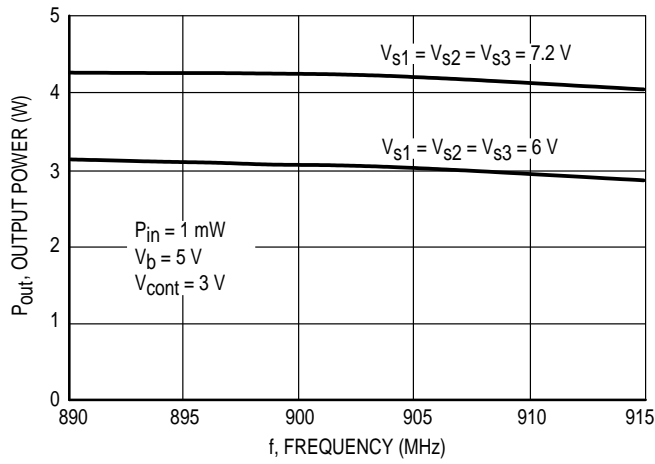


Figure 5. Output Power versus Frequency

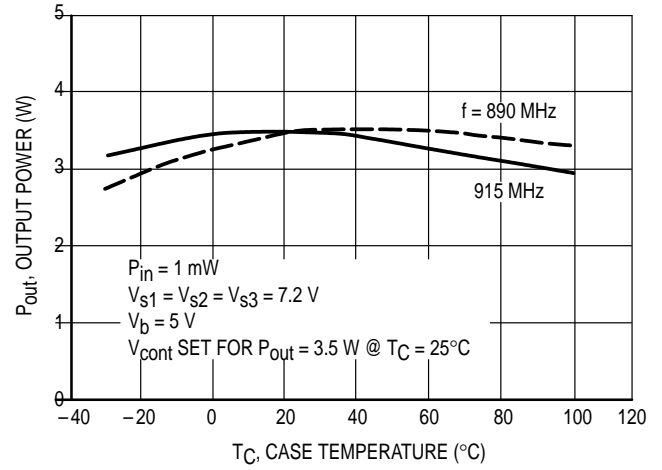


Figure 6. Output Power versus Case Temperature

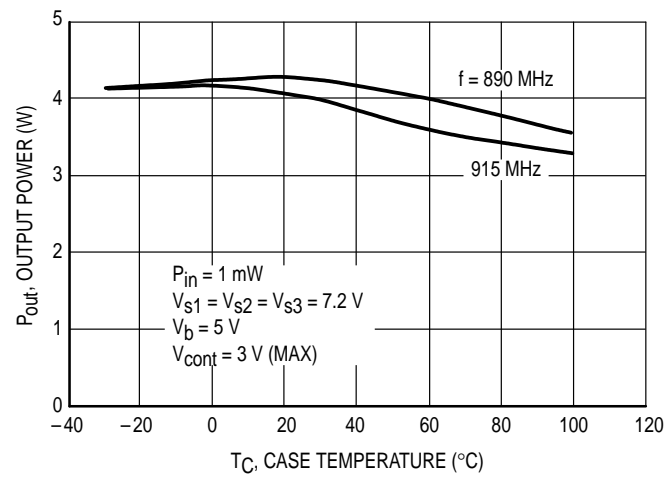


Figure 7. Output Power versus Case Temperature at Maximum Control Voltage

## APPLICATIONS INFORMATION

### NOMINAL OPERATION

All electrical specifications are based on the nominal conditions of  $V_{S1} = V_{S2} = V_{S3} = 7.2$  Vdc (Pins 2, 4, 5) and  $V_b = 5.0$  Vdc (Pin 3) for MHW953. Nominal conditions are  $V_{S1} = V_{S2} = 7.2$  Vdc (Pins 2 and 4) and  $V_b = 4.5$  Vdc (Pin 3) for MHW954. With these conditions, maximum current density on any device is  $1.5 \times 10^5$  A/cm<sup>2</sup> and maximum die temperature is 165°C. While the modules are designed to have excess gain margin with ruggedness, operation of these units outside the published specifications is not recommended unless prior communications regarding intended use have been made with the factory representative.

### GAIN CONTROL

The module output power should be limited to specified value. The preferred method of power control for the MHW953 is to fix  $V_{S1} = V_{S2} = V_{S3} = 7.2$  Vdc,  $V_b = 5.0$  Vdc,  $P_{in}$  (Pin 1) at 1.0 mW, and vary  $V_{cont}$  (Pin 1) voltage. For the MHW954, fix  $V_{S1} = V_{S2} = 7.2$  Vdc and  $V_b = 4.5$  Vdc; then vary  $P_{in}$  (Pin 1) to control  $P_{out}$  (Pin 5).

### DECOUPLING

Due to the high gain of the four stages and the module size limitation, external decoupling networks require careful consideration, Pins 2, 3, 4 and 5 are internally bypassed with a 0.018  $\mu$ F chip capacitor which is effective for frequencies from

5.0 MHz through 940 MHz. For bypassing frequencies below 5.0 MHz, networks equivalent to that shown in Figure 1 are recommended. Inadequate decoupling will result in spurious outputs at certain operating frequencies and certain phase angles of input and output VSWR.

### MOUNTING CONSIDERATIONS

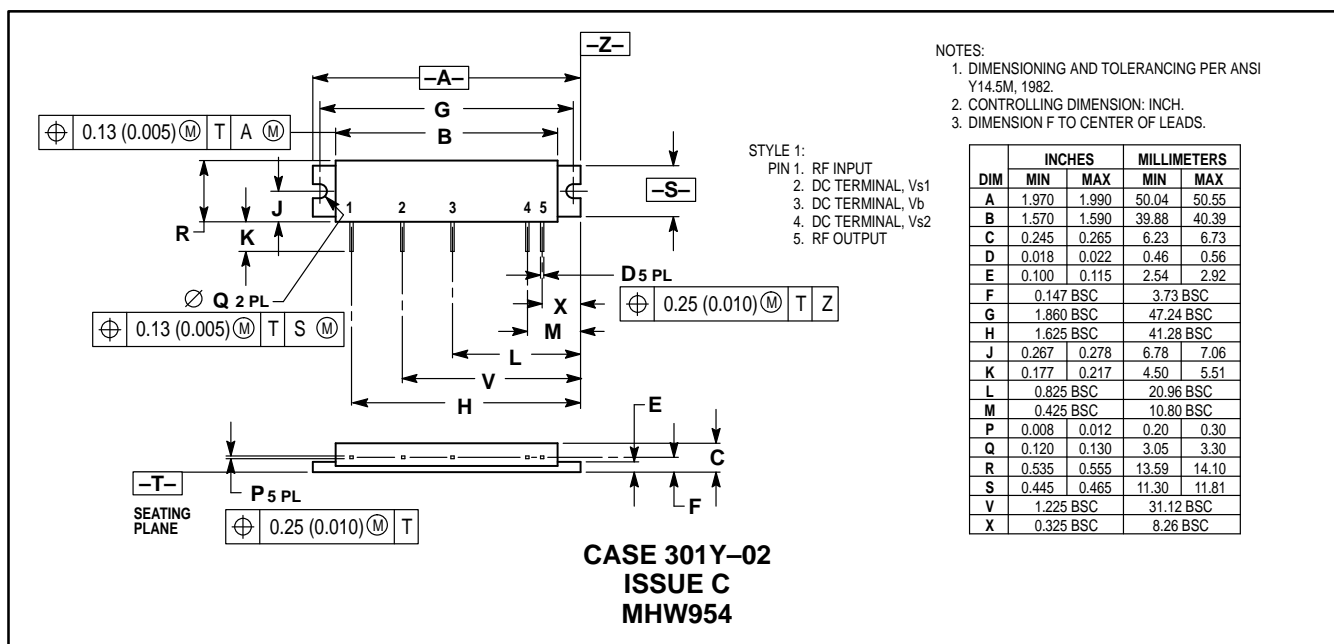
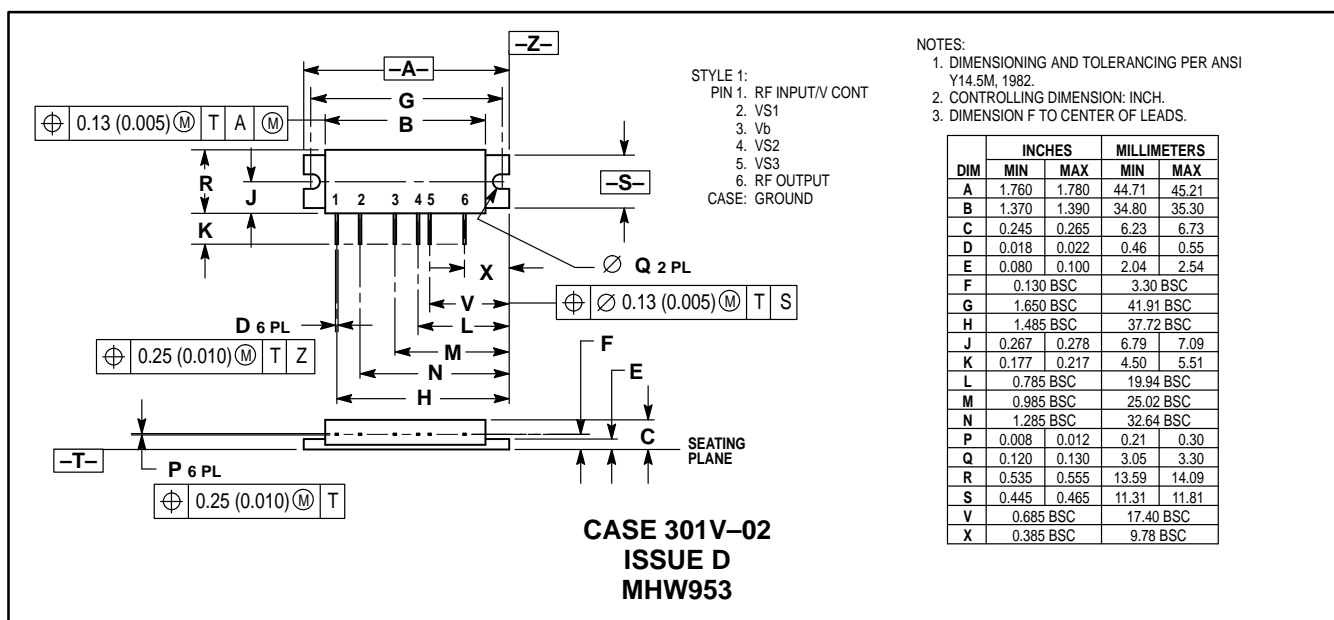
For the MHW903 Series module, mounting is generally accomplished by soldering the flange to a suitable heat sink. This can be done with a low temperature solder such as 52% In, 48% Sn and type "R" Flux which liquifies below 150°C. Under no circumstances should the MHW953 Series modules be heated to a temperature greater than  $\approx 165^\circ\text{C}$ . Internal construction of the module has been achieved using 36% Tin, 62% lead, 2% silver solder which liquifies at 179–180°C.


The modules are NOT hermetic. Do not immerse a module in a flux cleaning solution or other liquids under any circumstances.

### LOAD MISMATCH

During final test each module is load mismatch tested in a fixture having the identical decoupling networks described in Figure 1. Electrical conditions are  $V_{S1} = V_{S2} = V_{S3} = 9.0$  Vdc (Pins 2, 4, 5), and  $V_b = 5.0$  Vdc (Pin 3),  $P_{in} = 2.0$  mW (12.5% duty cycle, 4.6 ms period), VSWR equal to 10:1, and output power equal to 4.5 watts.

## PACKAGE DIMENSIONS



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MHW953/D

